LDMOS 3-stage integrated Doherty MMIC Rev. 1 — 10 January 2023

Product profile 1.

1.1 General description

The B10G4750N12DL is a 3-stage 12 W fully integrated Doherty MMIC solution using Ampleon's state of the art LDMOS technology. The carrier and peaking device, input splitter, output combiner, and output matching are integrated in a single package. This multiband device is perfectly suited as a general purpose device in the frequency range from 4700 MHz to 5000 MHz. Available in LGA outline.

Table 1. Performance

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$; $I_{Dq} = 31 \ mA$ (driver and final stages); $V_{GSa(peaking)} = V_{GSa(carrier)} - 0.50 V$; measured in an Ampleon application circuit.

Test signal	f	V _{DS}	P _{L(AV)}	G _p	ησ	
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
single carrier W-CDMA [1]	4900	28	1.585	31.1	32.6	-30.2

[1] Test signal: 1-carrier W-CDMA; PAR = 9.9 dB.

1.2 Features and benefits

- Integrated input splitter
- Integrated output combiner
- Very high efficiency
- Designed for broadband operation (frequency 4700 MHz to 5000 MHz)
- Independent control of carrier and peaking bias
- Integrated ESD protection
- Excellent thermal stability
- High power gain, input and output matched to impedance 50 Ω
- For RoHS compliance see the product details on the Ampleon website

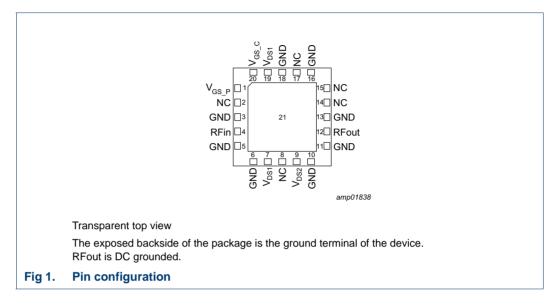
1.3 Applications

RF power MMIC for multi-carrier and multi-standard GSM, W-CDMA, LTE and NR small cell base stations in the 4700 MHz to 5000 MHz frequency range

LDMOS 3-stage integrated Doherty MMIC

2. Pinning information

2.1 Pinning



2.2 Pin description

Table 2. Pin description

Symbol	Pin	Description			
V _{GS_P}	1	gate-source voltage of peaking			
NC	2	not connected (connection to ground is allowed)			
GND	3	ground (connection to ground is required)			
RFin	4	RF input			
GND	5	ground (connection to ground is required)			
GND	6	ground (connection to ground is required)			
V _{DS1}	7	drain-source voltage of driver stages			
NC	8	not connected (connection to ground is allowed)			
V _{DS2}	9	drain-source voltage of final stages			
GND	10	ground (connection to ground is required)			
GND	11	ground (connection to ground is required)			
RFout	12	RF output			
GND	13	ground (connection to ground is required)			
NC	14	not connected (connection to ground is allowed)			
NC	15	not connected (connection to ground is allowed)			
GND	16	ground (connection to ground is required)			
NC	17	not connected (connection to ground is allowed)			
GND	18	ground (connection to ground is required)			

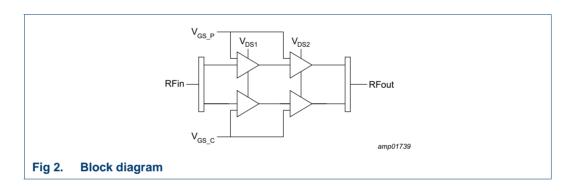
Table 2. Pin descriptioncontinued				
Symbol		Pin	Description	
V _{DS1}		19	drain-source voltage of driver stages	
V _{GS_C}		20	gate-source voltage of carrier	
GND		21	RF ground (connection to ground is required)	

3. Ordering information

Table 3.Ordering information

Package name	Orderable part number	12NC	Packing description	Min. orderable quantity (pieces)
LGA-7x7-20-2	B10G4750N12DLX	9349 605 89525	TR13; 3000-fold; 16 mm; dry pack	3000
	B10G4750N12DLZ	9349 605 89515	TR13; 1000-fold; 16 mm; dry pack	1000

4. Block diagram



5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage		-	65	V
V _{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-55	+125	°C
Tj	junction temperature	[1]	-	175	°C
T _{case}	case temperature	[1]	-	125	°C

[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

Thermal characteristics 6.

Table 5. **Thermal characteristics**

Measured for total device.

Symbol	Parameter	Conditions	Value	Unit
R _{th(j-c)}	-	$T_{case} = 90 \ ^{\circ}C; P_{L(AV)} = 1.585 \ W$ [1]	7.8	K/W
	case			

[1] When operated with a 1-carrier W-CDMA with PAR = 9.9 dB.

Characteristics 7.

Table 6. **DC** characteristics

 $T_{\text{case}} = 25 \, ^{\circ}\text{C}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Carrier			-		1	
V _{GSq}	gate-source quiescent voltage	$V_{DS} = 28 \text{ V}; \text{ I}_{D} = 30 \text{ mA}$	1.65	2.13	2.75	V
I _{GSS}	gate leakage current	V_{GS} = +9 V/–5 V; V_{DS} = 0 V	-	-	140	nA
Peaking						
I _{GSS}	gate leakage current	V_{GS} = +9 V/–5 V; V_{DS} = 0 V	-	-	140	nA
Final sta	ges					
I _{DSS}	drain leakage current	$V_{GS} = 0 V; V_{DS} = 60 V$	-	-	1.4	μA
Driver st	ages					
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 60 V	-	-	1.4	μA

RF characteristics Table 7.

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$; $V_{DS} = 28 \ V$; $I_{Dq} = 30 \ mA$ (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5 \ V$; $P_L = 1.585 \ W$; $f = 5 \ GHz$. Unless otherwise specified, measured in an Ampleon production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Test signal: CW pulsed						
G _p	power gain		27	30	-	dB
η _D	drain efficiency		26	32	-	%
RL _{in}	input return loss		-	-13	-8	dB
P _{L(3dB)}	output power at 3 dB gain compression		39.5	41	-	dBm

8. Application information

Table 8. Typical performance

 $T_{case} = 25 \text{ °C}$; $V_{DS} = 28 \text{ V}$; $I_{Dq} = 31 \text{ mA}$ (driver and final stages); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.50 \text{ V}$; Test signal: 1-carrier W-CDMA; PAR = 9.9 dB; unless otherwise specified, measured in an Ampleon 4700 MHz to 5000 MHz frequency band application circuit.

Symbol	Parameter	Conditions		Тур	Max	Unit
P _{L(3dB)}	output power at 3 dB gain compression	f = 4900 MHz	-	42.1	-	dBm
ηρ	drain efficiency	10.1 dB OBO (P _{L(AV)} = 32 dBm); f = 4900 MHz	-	32.6	-	%
G _p	power gain	P _{L(AV)} = 32 dBm; f = 4900 MHz	-	31.1	-	dB
G _{flat}	gain flatness	P _{L(AV)} = 32 dBm; f = 4700 MHz to 5000 MHz	-	0.9	-	dB
$ACPR_{5M}$	adjacent channel power ratio (5 MHz)	P _{L(AV)} = 32 dBm; f = 4900 MHz	-	-30.2	-	dBc
$\Delta G / \Delta T$	gain variation with temperature	f = 4850 MHz	-	0.08	-	dB/°C
К	Rollett stability factor	$T_{case} = -40 \text{ °C}; f = 0.6 \text{ GHz to } 8.1 \text{ GHz}$	-	>1	-	

[1] Pulsed CW power sweep measurement ($\delta = 10 \%$, t_p = 100 µs).

[2] S-parameters measured in a demo circuit.

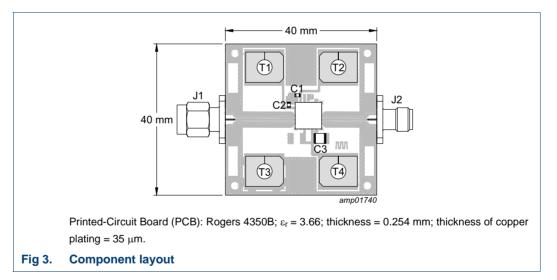


Table 9. Demo test circuit list of components

See <u>Figure 3</u> for component layout.

Component	Description	Value	Remarks
C1, C2	multilayer ceramic chip capacitor	1 μF, 25 V [1]	
C3	multilayer ceramic chip capacitor	10 μF, 50 V [1]	
J1	coaxial panel connector male		Huber+Suhner: 13_SMA-50-0-2-/111_N
J2	coaxial panel connector female		Huber+Suhner: 23_SMA-50-0-2-/111_N
T1, T2, T3, T4	PCB terminal	6.3 mm x 0.81 mm, 4.1 mm	TE connectivity

[1] Murata or capacitor of same quality.

8.1 Ruggedness in a Doherty operation

8.1.1 Output mismatch ruggedness

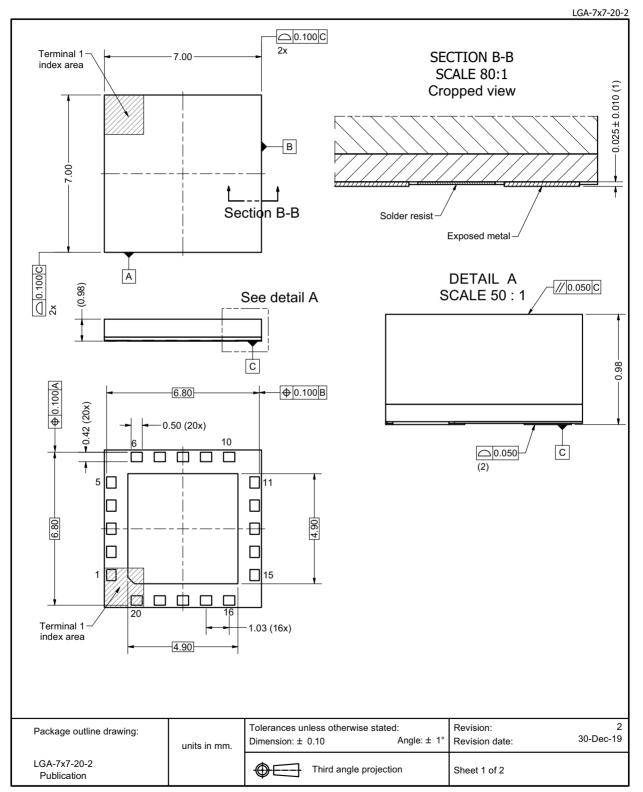
The B10G4750N12DL is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 32$ V; $I_{Dq} = 32$ mA (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5$ V; P_i corresponding to $P_{L(3dB)} - 5$ dB under $Z_S = 50 \Omega$ load; f = 5000 MHz (1-carrier W-CDMA); $T_{case} = 25$ °C.

8.1.2 Wideband noise ruggedness

The B10G4750N12DL is capable of withstanding an AWGN (Additive White Gaussian Noise) with 11.2 dB PAR, OBW (Occupied BandWidth) of 900 MHz, under the following conditions: $V_{DS} = 32$ V; $I_{Dq} = 32$ mA (carrier); $V_{GSq(peaking)} = V_{GSq(carrier)} - 0.5$ V; 3 dB P_i overdrive from P_L = 34 dBm (corresponding to P_{L(3dB)} - 9 dB); f = 4850 MHz; $T_{case} = 25$ °C.

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9. Package outline





LDMOS 3-stage integrated Doherty MMIC

LGA-7x7-20-2

			awing Notes		
	Iten	m Description			
	1	M	etal thickness of solder pads.		
	2	Flatne	ess with respect to exposed meta		
	L	1			
Package outline drawing:			less otherwise stated:	Revision:	2
	units in mm.	Dimension: ±	0.10 Angle: ± 1	Revision date:	30-Dec-19
LGA-7x7-20-2			Third could get 1		
			Third angle projection	Sheet 2 of 2	

Fig 5. Package outline LGA-7x7-20-2 (sheet 2 of 2)

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10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10.ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

11. Abbreviations

Table 11. Abbreviations				
Acronym	Description			
CW	Continuous Wave			
ESD	ElectroStatic Discharge			
GSM	Global System for Mobile Communications			
LDMOS	Laterally Diffused Metal Oxide Semiconductor			
LTE	Long Term Evolution			
MMIC	Monolithic Microwave Integrated Circuit			
MTF	Median Time to Failure			
NR	New Radio			
OBO	Output Back Off			
PAR	Peak-to-Average Ratio			
RoHS	Restriction of Hazardous Substances			
VSWR	Voltage Standing Wave Ratio			
W-CDMA	Wideband Code Division Multiple Access			

12. Revision history

Table 12.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
B10G4750N12DL v.1	20230110	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 10 January 2023 Document identifier: B10G4750N12DL